NSN 5961-01-331-2896

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-331-2896 **Inclosure Material:** Metal and ceramic **Overall Length:** 25.2 millimeters **Overall Height:** 7.5 millimeters **Overall Width:** 15.9 millimeters **End Application:** Tactical air operations module an/tyq-2 (v) 1 **Mounting Facility Quantity:** 2 **Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 drain to source voltage **Current Rating Per Characteristic:** 6.00 amperes drain current **Power Rating Per Characteristic:** 30.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**